HCPL-4506/J456/0466 HCNW4506 Intelligent Power Module and Gate Drive Interface

Intelligent Power Module and Gate Drive Interface Optocouplers

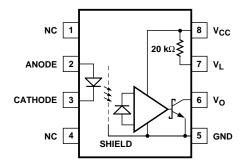
Data Sheet

Description

The HCPL-4506 and HCPL-0466 contain a GaAsP LED while the HCPL-J456 and the HCNW4506 contain an AlGaAs LED. The LED is optically coupled to an integrated high gain photo detector. Minimized propagation delay difference between devices makes these optocouplers excellent solutions for improving inverter efficiency through reduced switching dead time.

An on chip 20 k Ω output pull-up resistor can be enabled by shorting output pins 6 and 7, thus eliminating the need for an external pull-up resistor in common IPM applications. Specifications and performance plots are given for typical IPM applications.

Functional Diagram



Truth Table

LED	Vo
ON	L
OFF	Н

The connection of a 0.1 μF bypass capacitor between pins 5 and 8 is recommended.

Features

- Performance specified for bommon IPM applications over industrial temperature range: -40°C to 100°C
- · Fast maximum propagation delays
 - $t_{PHL} = 480 \text{ ns}$
 - t_{PLH} = 550 ns
- Minimized Pulse Width Distortion PWD = 450 ns
- + 15 kV/ μs minimum common mode transient immunity at $V_{CM} = 1500 \; V$
- CTR > 44% at $I_F = 10 \text{ mA}$

· Safety approval:

UL Recognized

-3750 V rms / 1 min. for HCPL-4506/0466/J456 -5000 V rms / 1 min. for HCPL-4506 Option 020 and HCNW4506

CSA Approved IEC/EN/DIN EN 60747-5-2 Approved

- -V_{IORM} = 560 Vpeak for HCPL-0466 Option 060
- $-V_{IORM} = 630$ Vpeak for HCPL-4506 Option 060
- -V_{IORM} = 891 Vpeak for HCPL-J456
- -V_{IORM} = 1414 Vpeak for HCNW4506

Applications

- · IPM isolation
- Isolated IGBT/MOSFET gate drive
- · AC and brushless DC motor drives
- Industrial inverters

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.



Selection Guide

Package Type	Standard 8-Pin DIP (300 Mil)	White Mold 8-Pin DIP (300 Mil)	Small Outline SO8	Widebody (400 Mil)	Hermetic*
Part Number	HCPL-4506	HCPL-J456	HCPL-0466	HCNW4506	HCPL-5300 HCPL-5301
IEC/EN/DIN EN 60747- 5-2 Approval	V _{IORM} = 630 Vpeak (Option 060)	V _{IORM} = 891 Vpeak	V _{IORM} = 560 Vpeak (Option 060)	V _{IORM} = 1414 Vpeak	_

*Technical data for these products are on separate Avago publications.

Ordering Information

Specify Part Number followed by Option Number (if desired).

Example:

HCPL-4506#XXXX

 020 = UL 5000 V rms/1 minute Option** for HCPL-4506 Only.

 060 = IEC/EN/DIN EN 60747-5-2 Option** for HCPL-4506/0466.

 300 = Gull Wing Lead Option for HCPL-4506/J456, HCNW4506.

 500 = Tape and Reel Packaging Option

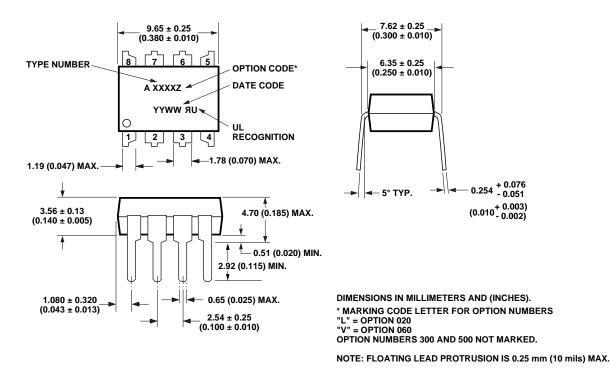
 XXXE = Lead Free Option

Option data sheets are available. Contact Avago sales representative or authorized distributor for information.

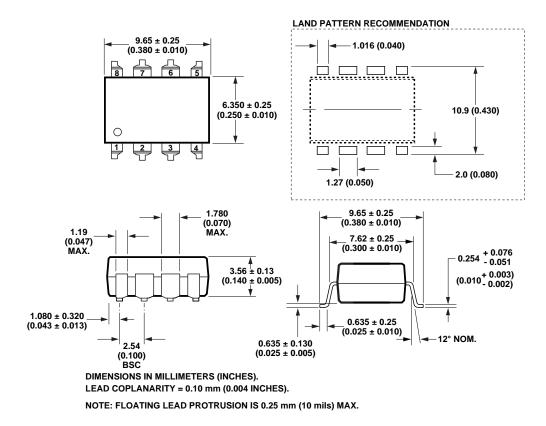
**Combination of Option 020 and Option 060 is not available.

Remarks: The notation "#" is used for existing products, while (new) products launched since 15th July 2001 and lead free option will use "-"

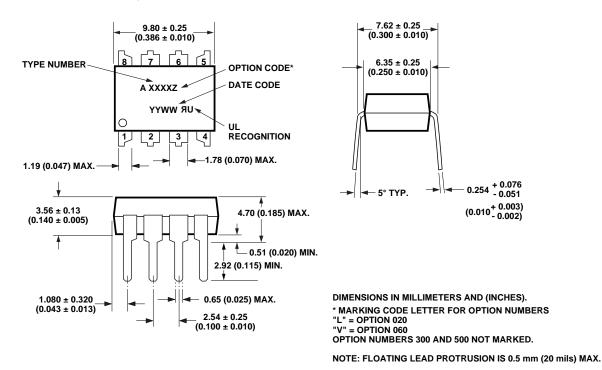
Package Outline Drawings HCPL-4506 Outline Drawing



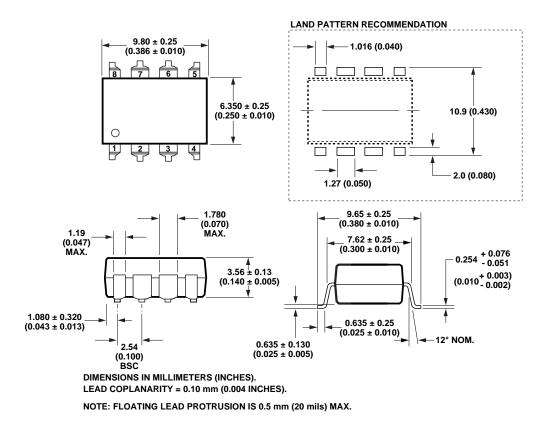
HCPL-4506 Gull Wing Surface Mount Option 300 Outline Drawing



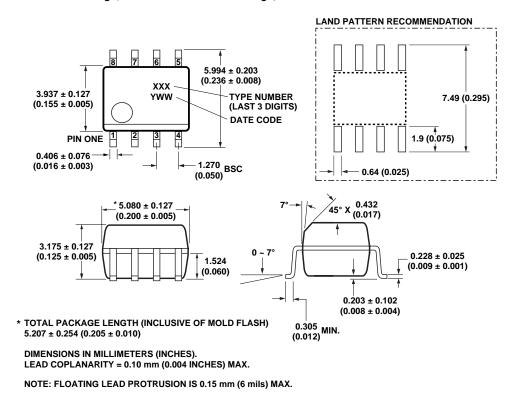
Package Outline Drawings HCPL-J456 Outline Drawing



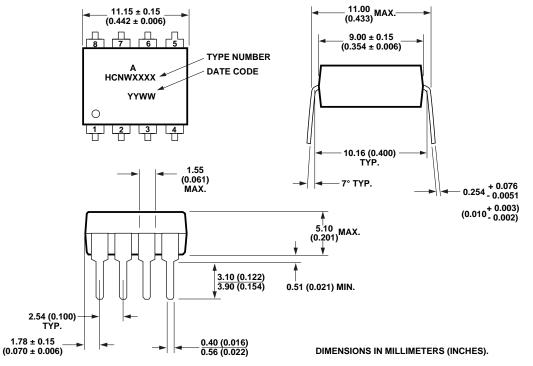
HCPL-J456 Gull Wing Surface Mount Option 300 Outline Drawing



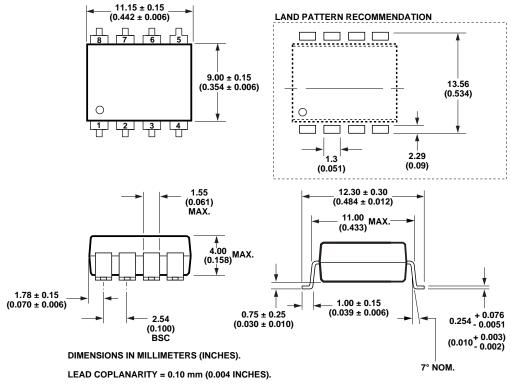
HCPL-0466 Outline Drawing (8-Pin Small Outline Package)



HCNW4506 Outline Drawing (8-Pin Widebody Package)

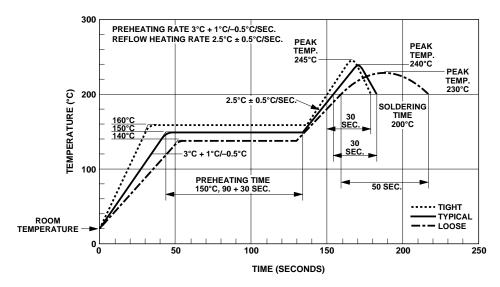


HCNW4506 Gull Wing Surface Mount Option 300 Outline Drawing



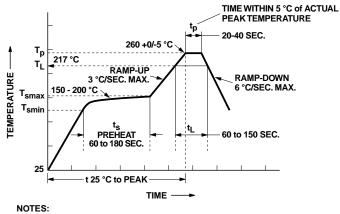
NOTE: FLOATING LEAD PROTRUSION IS 0.25 mm (10 mils) MAX.

Solder Reflow Temperature Profile



Note: Use of non-chlorine-activated fluxes is highly recommended.

Recommended Pb-Free IR Profile



THE TIME FROM 25 °C to PEAK TEMPERATURE = 8 MINUTES MAX. T_{smax} = 200 °C, T_{smin} = 150 °C

Note: Use of non-chlorine-activated fluxes is highly recommended.

Regulatory Information

The devices contained in this data sheet have been approved by the following agencies:

Agency/Standard		HCPL-4506	HCPL-J456	HCPL-0466	HCNW4506
Underwriters Laboratories (UL) Recognized under UL 1577, Component Recognized Program, Category FPQU2, File E55361	UL 1577	v	V	r	~
Canadian Standards Association (CSA) File CA88324	Component Acceptance Notice #5	~	v	~	r
Verband Deutscher Electrotechniker (VDE)	DIN VDE 0884 (June 1992)	~	~		~
IEC/EN/DIN EN 60747-5-2 Approved under: IEC 60747-5-2:1997 + A1:2002 EN 60747-5-2:2001 + A1:2002 DIN EN 60747-5-2 (VDE 0884 Teil 2):2002	3-01	v	v	v	r

Insulation and Safety Related Specifications

			Va	lue			
Parameter	Symbol	HCPL-4506	HCPL-J456	HCPL-0466	HCNW4506	Units	Conditions
Minimum External Air Gap (External Clearance)	L(101)	7.1	7.4	4.9	9.6	mm	Measured from input terminals to output terminals, shortest distance through air.
Minimum External Tracking (External Creepage)	L(102)	7.4	8.0	4.8	10.0	mm	Measured from input terminals to output terminals, shortest distance path along body.
Minimum Internal Plastic Gap (Internal Clearance)		0.08	0.5	0.08	1.0	mm	Through insulation distance, conductor to conductor, usually the direct distance between the photoemitter and photodetector inside the optocoupler cavity.
Minimum Internal Tracking (Internal Creepage)		NA	NA	NA	4.0	mm	Measured from input terminals to output terminals, along internal cavity.
Tracking Resistance (Comparative Tracing Index)	CTI	≥175	≥175	≥175	≥200	Volts	DIN IEC 112/VDE 0303 Part 1
Isolation Group		Illa	Illa	Illa	Illa		Material Group (DIN VDE 0110, 1/89, Table 1)

All Avago data sheets report the creepage and clearance inherent to the optocoupler component itself. These dimensions are needed as a starting point for the equipment designer when determining the circuit insulation requirements. However, once mounted on a printed circuit board, minimum creepage and clearance requirements must be met as specified for individual equipment standards. For creepage, the shortest distance path along the surface of a printed circuit board between the solder fillets of the input and output leads must be considered. There are recommended techniques such as grooves and ribs which may be used on a printed circuit board to achieve desired creepage and clearances. Creepage and clearance distances will also change depending on factors such as pollution degree and insulation level.

IEC/EN/DIN EN 60747-5-2 Insulation Related Charac	teristics
---	-----------

		HCPL-0466	HCPL-4506			
Description	Symbol	Option 060	Option 060	HCPL-J456	HCNW4506	Unit
Installation classification per						
DIN VDE 0110/1.89, Table 1						
for rated mains voltage \leq 150 V rms		I-IV	I-IV	I-IV	I-IV	
for rated mains voltage \leq 300 V rms		1-111	I-IV I-III	I-IV -	I-IV I-IV	
for rated mains voltage \leq 450 V rms for rated mains voltage \leq 600 V rms			1-111	-	I-IV	
for rated mains voltage ≤ 000 V rms				1-111	-	
Climatic Classification		55/100/21	55/100/21	55/100/21	55/100/21	
Pollution Degree		2	2	2	2	
(DIN VDE 0110/1.89)		2			2	
Maximum Working	VIORM	560	630	891	1414	V _{peak}
Insulation Voltage	ionini					pour
Input to Output Test Voltage,						
Method b* V_{IORM} x 1.875 = V_{PR} ,						
100% Production Test with t _m =	V _{PR}	1050	1181	1670	2652	V _{peak}
1 sec, Partial Discharge < 5pC						
Input to Output Test Voltage,						
Method a [*] V_{IORM} x 1.5 = $V_{PR'}$						
Type and Sample Test, $t_m = 60$ sec,	V _{PR}	840	945	1336	2121	V _{peak}
Partial Discharge < 5pC						
Highest Allowable Overvoltage*	VIOTM	4000	6000	6000	8000	V _{peak}
(Transient Overvoltage, t _{ini} = 10 sec)						
Safety Limiting Values – maximum						
values allowed in the event of a fail-						
ure, also see Thermal Derating curve.		150	475	175	150	
Case Temperature	T _S	150	175	175	150	°C
Input Current Output Power	I _{S INPUT}	150 600	230 600	400 600	400 700	mA mW
	P _{S OUTPUT}					
Insulation Resistance at T_s ,	R _S	≥ 10 ⁹	≥10 ⁹	≥109	≥10 ⁹	Ω
$V_{10} = 500 \text{ V}$						

*Refer to the optocoupler section of the Designer's Catalog, under regulatory information (IEC/EN/DIN EN 60747-5-2) for a detailed description of Method a and Method b partial discharge test profiles.

Note: These optocouplers are suitable for "safe electrical isolation" only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.

Note: Insulation Characteristics are per IEC/EN/DIN EN 60747-5-2.

Note: Surface mount classification is Class A in accordance with CECC 00802.

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units		
Storage Temperature	Ts	-55	125	٥C		
Operating Temperature		T _A	-40	100	٥C	
Average Input Current ^[1]		I _{F(avg)}		25	mA	
Peak Input Current ^[2] (50% duty cycle	e, ≤1 ms pulse width)	I _{F(peak)}		50	mA	
Peak Transient Input Current (<1 µs	pulse width, 300 pps)	I _{F(tran)}		1.0	A	
Reverse Input Voltage (Pin 3-2)	HCPL-4506, HCPL-0466	V _R		5	Volts	
	HCPL-J456, HCNW4506			3	1	
Average Output Current (Pin 6)		I _{O(avg)}		15	mA	
Resistor Voltage (Pin 7)		V ₇	-0.5	V _{CC}	Volts	
Output Voltage (Pin 6-5)		Vo	-0.5	30	Volts	
Supply Voltage (Pin 8-5)		V _{CC}	-0.5	30	Volts	
Output Power Dissipation ^[3]		Po		100	mW	
Total Power Dissipation ^[4]		PT		145	mW	
Lead Solder Temperature (HCPL-450	6, HCPL-J456)	260°C for	10 s, 1.6 mm	below seatir	ig plane	
Lead Solder Temperature (HCNW450		260°C (up to seat	for 10 s ing plane)			
Infrared and Vapor Phase Reflow Ter (HCPL-0466 and Option 300)	nperature	See Pac	kage Outlin	e Drawings	Section	

Recommended Operating Conditions

···· · · · · · · · · · · · · · · · · ·										
Parameter	Symbol	Min.	Max.	Units						
Power Supply Voltage	V _{CC}	4.5	30	Volts						
Output Voltage	Vo	0	30	Volts						
Input Current (ON)	I _{F(on)}	10	20	mA						
Input Voltage (OFF)	V _{F(off)} *	-5	0.8	V						
Operating Temperature	T _A	-40	100	°C						

*Recommended $V_{F(OFF)}$ = -3 V to 0.8 V for HCPL-J456, HCNW4506.

Electrical Specifications

Parameter	Symbol	Device	Min.	Тур.*	Max.	Units	Test Conditions	Fig.	Note
Current Transfer Ratio	CTR		44	90		%	$I_F = 10 \text{ mA},$ $V_0 = 0.6 \text{ V}$		5
Low Level Output Current	I _{OL}		4.4	9.0		mA	$I_F = 10 \text{ mA},$ $V_0 = 0.6 \text{ V}$	1, 2	
Low Level Output Voltage	V _{OL}			0.3	0.6	V	I ₀ = 2.4 mA		
Input Threshold Current	I _{TH}	HCPL-4506 HCPL-0466 HCNW4506		1.5	5	mA	$V_0 = 0.8 V,$ $I_0 = 0.75 mA$	1	16
		HCPL-J456		0.6					
High Level Output Current	I _{OH}			5	50	μA	$V_{F} = 0.8 V$	3	
High Level Supply Current	I _{CCH}			0.6	1.3	mA	$V_F = 0.8 V,$ $V_O = Open$		16
Low Level Supply Current	I _{CCL}			0.6	1.3	mA	I _F = 10 mA, V ₀ = Open		16
Input Forward Voltage	V _F	HCPL-4506 HCPL-0466		1.5	1.8	V	I _F = 10 mA	4	
		HCPL-J456	1.2	1.6	1.95			5	
		HCNW4506		1.6	1.85				
Temperature Coefficient of Forward Voltage	$\Delta V_F / \Delta T_A$	HCPL-4506 HCPL-0466		-1.6		mV/°C	I _F = 10 mA		
		HCPL-J456 HCNW4506		-1.3					
Input Reverse Breakdown Voltage	BV _R	HCPL-4506 HCPL-0466	5			V	I _R = 10 μA		
		HCPL-J456 HCNW4506	3				I _R = 100 μA		
Input Capacitance	C _{IN}	HCPL-4506 HCPL-0466		60		pF	$ f = 1 MHz, \\ V_F = 0 V $		
		HCPL-J456 HCNW4506		72					
Internal Pull-up Resistor	RL		14	20	25	kΩ	$T_A = 25^{\circ}C$		12, 13
Internal Pull-up Resistor Temperature Coefficient	$\Delta R_L / \Delta T_A$			0.014		kΩ/°C			

Over recommended operating conditions unless otherwise specified: $T_{A} = -40^{\circ}$ C to $+100^{\circ}$ C, $V_{CC} = +4.5$ V to 30 V, $I_{E(op)} = 10$ mA to 20 mA, $V_{E(off)} = -5$ V to 0.8 V[†]

*All typical values at 25°C, V_{CC} = 15 V. †V_{F(off)} = -3 V to 0.8 V for HCPL-J456, HCNW4506.

Switching Specifications (R_L= 20 k Ω External)

					1(0	,			
Parameter	Symbol	Min.	Тур.*	Max.	Units	Test C	onditions	Fig.	Note
Propagation Delay Time to Logic HCPL-J456	T _{PHL}	30	200	400 480	ns	C _L = 100 pF	$I_{F(on)} = 10 \text{ mA},$ $V_{F(off)} = 0.8 \text{ V},$	6, 8, 10-	11, 14,
Low at Output	4		100		1	C _L = 10 pF	$V_{\rm CC} = 15.0 \rm V_{c}$	13	16
Propagation Delay Time to High	T _{PLH}	270	400	550	ns	$C_L = 100 \text{ pF}$	V _{THLH} = 2.0 V, V _{THHL} = 1.5 V		
Output Level			130			C _L = 10 pF			
Pulse Width Distortion	PWD		200	450	ns	$C_L = 100 \text{ pF}$			20
Propagation Delay Difference Between Any 2 Parts	t _{PLH} -t _{PHL}	-150	200	450	ns				17
Output High Level Common Mode Transient Immunity	CM _H	15	30		kV∕µs	$I_F = 0 \text{ mA},$ $V_0 > 3.0 \text{ V}$	$V_{CC} = 15.0 V,$ $C_L = 100 pF,$ $V_{CM} = 1500 V_{p-p}$	7	18
Output Low Level Common Mode Transient Immunity	CM _L	15	30		kV∕µs	I _F = 10 mA V ₀ < 1.0 V	$T_A = 25^{\circ}C$		19

Over recommended operating conditions unless otherwise specified:
$T_A = -40^{\circ}C$ to $+100^{\circ}C$, $V_{CC} = +4.5$ V to 30 V, $I_{F(on)} = 10$ mA to 20 mA, $V_{F(off)} = -5$ V to 0.8 V†

Switching Specifications (R_L= Internal Pull-up)

Over recommended operating conditions unless otherwise specified: $T_A = -40^{\circ}C$ to $+100^{\circ}C$, $V_{CC} = +4.5$ V to 30 V, $I_{F(on)} = 10$ mA to 20 mA, $V_{F(off)} = -5$ V to 0.8 V†

Parameter	Symbol	Min.	Тур.*	Max.	Units	Test	Conditions	Fig.	Note
Propagation Delay Time to Logic HCPL-J456 Low at Output	t _{PHL}	20	200	400 485	ns		6, 9	11-14, 16	
Propagation Delay Time to High Output Level	t _{PLH}	220	450	650	ns				
Pulse Width Distortion	PWD		250	500	ns				20
Propagation Delay Difference Between Any 2 Parts	t _{PLH} -t _{PHL}	-150	250	500	ns				17
Output High Level Common Mode Transient Immunity	CM _H		30		kV∕µs	$I_F = 0 \text{ mA}, V_0 > 3.0 \text{ V}$	$\label{eq:V_CC} \begin{array}{l} V_{CC} = 15.0 \ V, \\ C_L = 100 \ pF, \\ V_{CM} = 1500 \ V_{p\text{-}p}, \end{array}$	7	18
Output Low Level Common Mode Transient Immunity	CM _L		30		kV∕µs	I _F = 16 mA, V ₀ < 1.0 V	$T_A = 25^{\circ}C$		19
Power Supply Rejection	PSR		1.0		V _{p-p}	Square Wave, t _{RISE} , t _{FALL} > 5 ns, no bypass capacitors			16

*All typical values at 25°C, V_{CC} = 15 V. † $V_{F(off)}$ = -3 V to 0.8 V for HCPL-J456, HCNW4506.

Package Characteristics

Parameter	Sym.	Device	Min.	Тур.*	Max.	Units	Test Conditions	Fig.	Note
Input-Output Momentary	V _{ISO}	HCPL-4506	3750			V rms	RH < 50%		6,7,10
Withstand Voltage†		HCPL-0466					t = 1 min.		
		HCPL-J456	3750				T _A = 25°C		6,8,10
		HCPL-4506	5000						6,9,
		Option020							15
		HCNW4506	5000						6,9,10
Resistance	R _{I-0}	HCPL-4506		10 ¹²			V _{I-0} = 500 Vdc		6
(Input-Output)		HCPL-J456				Ω			
		HCPL-0466							
		HCNW4506	10 ¹²	10 ¹³					
Capacitance	C _{I-0}	HCPL-4506		0.6		pF	f = 1 MHz		6
(Input-Output)		HCPL-0466							
		HCPL-J456		0.8					
		HCNW4506	İ	0.5					

Over recommended temperature ($T_A = -40^{\circ}$ C to 100° C) unless otherwise specified.

*All typical values at 25°C, V_{CC} = 15 V.

The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating refer to the IEC/EN/DIN EN 60747-5-2 Insulation Related Characteristics Table (if applicable), your equipment level safety specification or Avago Application Note 1074 entitled "Optocoupler Input-Output Endurance Voltage," publication number 5963-2203E.

Notes:

- 1. Derate linearly above 90°C free-air temperature at a rate of 0.8 mA/°C.
- 2. Derate linearly above 90°C free-air temperature at a rate of 1.6 mA/°C.
- 3. Derate linearly above 90°C free-air temperature at a rate of 3.0 mW/°C.
- Derate linearly above 90°C free-air temperature at a rate of 4.2 mW/°C.
- CURRENT TRANSFER RATIO in percent is defined as the ratio of output collector current (I₀) to the forward LED input current (I_F) times 100.
- 6. Device considered a two-terminal device: Pins 1, 2, 3, and 4 shorted together and Pins 5, 6, 7, and 8 shorted together.
- In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage ≥4500 V rms for 1 second (leakage detection current limit, I_{L0} ≤5 μA).
- 8. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage \ge 4500 V rms for 1 second (leakage detection current limit, $l_{i-0} \le 5 \mu$ A).

- 9. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage ≥ 6000 V rms for 1 second (leakage detection current limit, $I_{I-0} \leq 5 \mu A$).
- 10. This test is performed before the 100% Production test shown in the IEC/EN/DIN EN 60747-5-2 Insulation Related Characteristics Table, if applicable.
- 11. Pulse: f = 20 kHz, Duty Cycle = 10%.
- 12. The internal 20 k Ω resistor can be used by shorting pins 6 and 7 together.
- Due to tolerance of the internal resistor, and since propagation delay is dependent on the load resistor value, performance can be improved by using an external 20 kΩ 1% load resistor. For more information on how propagation delay varies with load resistance, see Figure 8.
- 14. The $R_L = 20 k\Omega$, $C_L = 100 pF$ load represents a typical IPM (Intelligent Power Module) load.
- 15. See Option 020 data sheet for more information.

- Use of a 0.1 μF bypass capacitor connected between pins 5 and 8 can improve performance by filtering power supply line noise.
- The difference between t_{PLH} and t_{PHL} between any two devices under the same test condition. (See IPM Dead Time and Propagation Delay Specifications section.)
- 18. Common mode transient immunity in a Logic High level is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM} , to assure that the output will remain in a Logic High state (i.e., $V_0 > 3.0$ V).
- 19. Common mode transient immunity in a Logic Low level is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM} , to assure that the output will remain in a Logic Low state (i.e., $V_0 < 1.0$ V).
- 20. Pulse Width Distortion (PWD) is defined as |t_{PHL} - t_{PLH}| for any given device.

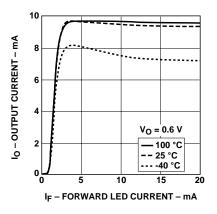


Figure 1. Typical transfer characteristics.

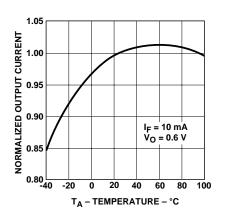


Figure 2. Normalized output current vs. temperature.

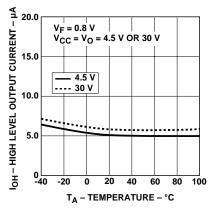
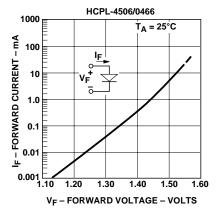


Figure 3. High level output current vs. temperature.



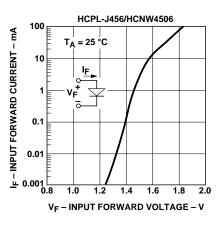
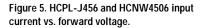


Figure 4. HCPL-4506 and HCPL-0466 input current vs. forward voltage.



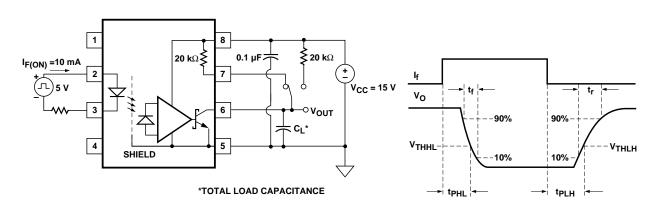
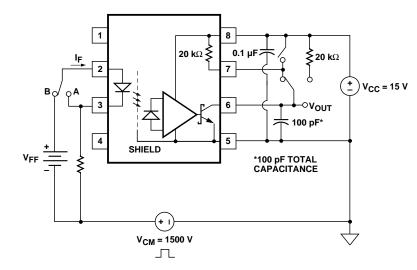


Figure 6. Propagation delay test circuit.



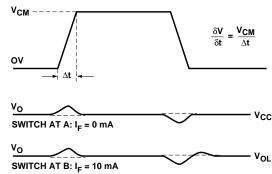
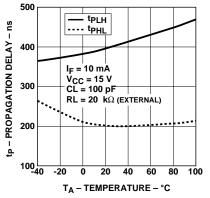
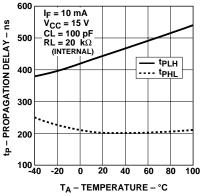


Figure 7. CMR test circuit. Typical CMR waveform.





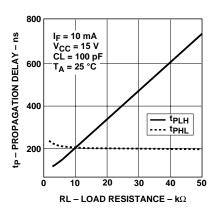


Figure 8. Propagation delay with external 20 kΩ RL vs. temperature.

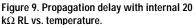


Figure 10. Propagation delay vs. load resistance.

500

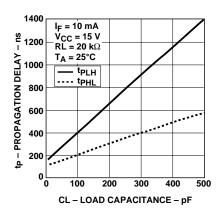


Figure 11. Propagation delay vs. load

I_F = 10 mA CL = 100 pF tp – PROPAGATION DELAY – ns 1200 RL = 20 kΩ T_A = 25°C 1000 - ^tPLH ---- t_{PHL} 800 600 400 200 0 5 20 25 15 30 10 V_{CC} - SUPPLY VOLTAGE - V

tPLH t_P – PROPAGATION DELAY – ns ---- ^tPHL 400 V_{CC} = 15 V CL = 100 pF 300 $RL = 20 k\Omega$ T_A = 25°C 200 100 L 0 10 15 20 5 IF - FORWARD LED CURRENT - mA

Figure 12. Propagation delay vs. supply voltage.

Figure 13. Propagation delay vs. input current.

kΩ RL vs. temperature.

1400

capacitance.

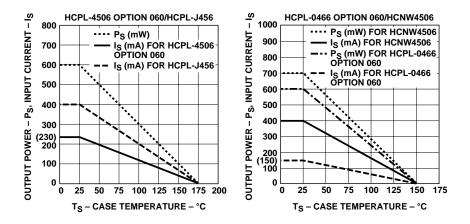


Figure 14. Thermal derating curve, dependence of safety limiting value with case temperature per IEC/EN/DIN EN 60747-5-2.

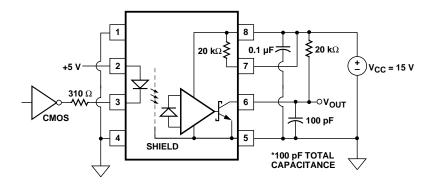


Figure 15. Recommended LED drive circuit.

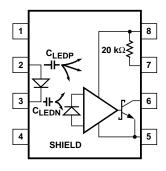


Figure 16. Optocoupler input to output capacitance model for unshielded optocouplers.

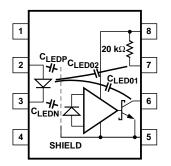


Figure 17. Optocoupler input to output capacitance model for shielded optocouplers.

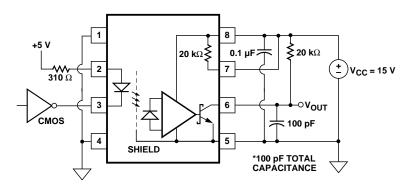


Figure 18. LED drive circuit with resistor connected to LED anode (not recommended).

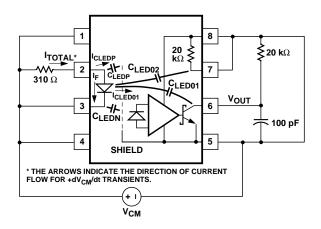


Figure 19. AC equivalent circuit for Figure 18 during common mode transients.

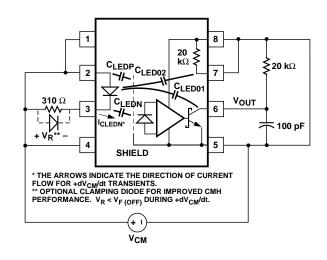


Figure 20. AC equivalent circuit for Figure 15 during common mode transients.

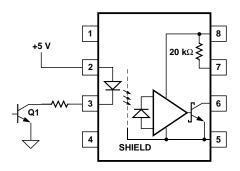


Figure 21. Not recommended open collector LED drive circuit.

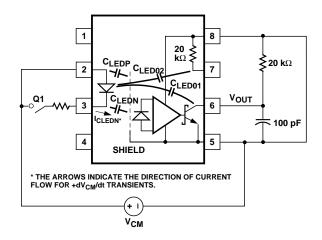


Figure 22. AC Equivalent circuit for Figure 21 during common mode transients.

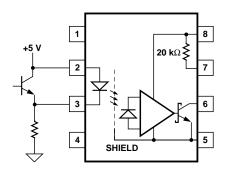


Figure 23. Recommended LED drive circuit for ultra high CMR.

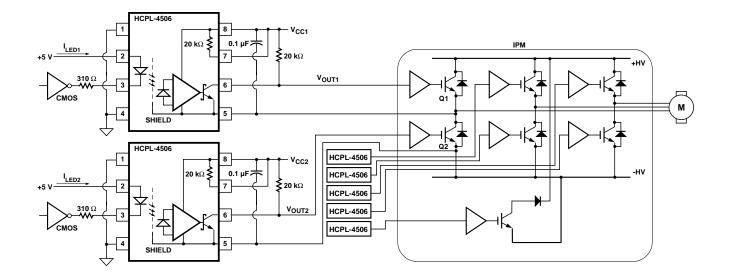
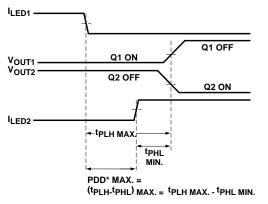


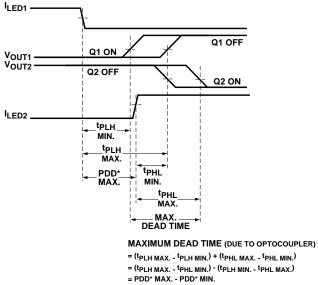
Figure 24. Typical application circuit.



*PDD = PROPAGATION DELAY DIFFERENCE

NOTE: THE PROPAGATION DELAYS USED TO CALCULATE PDD ARE TAKEN AT EQUAL TEMPERATURES.

Figure 25. Minimum LED skew for zero dead time.



= (t_{PLH MAX.} - t_{PLH MIN.}) + (t_{PHL MAX.} - t_{PHL MIN.})

*PDD = PROPAGATION DELAY DIFFERENCE NOTE: THE PROPAGATION DELAYS USED TO CALCULATE THE MAXIMUM DEAD TIME ARE TAKEN AT EQUAL TEMPERATURES.

Figure 26. Waveforms for dead time calculation.

LED Drive Circuit Considerations for Ultra High CMR Performance

Without a detector shield, the dominant cause of optocoupler CMR failure is capacitive coupling from the input side of the optocoupler, through the package, to the detector IC as shown in Figure 16. The HCPL-4506 series improve CMR performance by using a detector IC with an optically transparent Faraday shield, which diverts the capacitively coupled current away from the sensitive IC circuitry. However, this shield does not eliminate the capacitive coupling between the LED and the optocoupler output pins and output ground as shown in Figure 17. This capacitive coupling causes perturbations in the LED current during common mode transients and becomes the major source of CMR failures for a shielded optocoupler. The main design objective of a high CMR LED drive circuit becomes keeping the LED in the proper state (on or off) during common mode transients. For example, the recommended application circuit (Figure 15), can achieve 15 kV/ μs CMR while minimizing component complexity. Note that a CMOS gate is recommended in Figure 15 to keep the LED off when the gate is in the high state.

Another cause of CMR failure for a shielded optocoupler is direct coupling to the optocoupler output pins through C_{LEDO1} and C_{LEDO2} in Figure 17. Many factors influence the effect and magnitude of the direct coupling including: the use of an internal or external output pull-up resistor, the position of the LED current setting resistor, the connection of the unused input package pins, and the value of the capacitor at the optocoupler output (C_L).

Techniques to keep the LED in the proper state and minimize the effect of the direct coupling are discussed in the next two sections.

CMR with the LED On (CMRL)

A high CMR LED drive circuit must keep the LED on during common mode transients. This is achieved by overdriving the LED current beyond the input threshold so that it is not pulled below the threshold during a transient. The recommended minimum LED current of 10 mA provides adequate margin over the maximum I_{TH} of 5.0 mA (see Figure 1) to achieve $15 \text{ kV/}\mu\text{s}$ CMR. Capacitive coupling is higher when the internal load resistor is used (due to C_{LEDO2}) and an $I_F = 16$ mA is required to obtain 10 kV/µs CMR.

The placement of the LED current setting resistor effects the ability of the drive circuit to keep the LED on during transients and interacts with the direct coupling to the optocoupler output. For example, the LED resistor in Figure 18 is connected to the anode. Figure 19 shows the AC equivalent circuit for Figure 18 during common mode transients. During a +dVcm/dt in Figure 19. the current available at the LED anode (Itotal) is limited by the series resistor. The LED current (I_F) is reduced from its DC value by an amount equal to the current that flows through C_{LEDP} and C_{LEDO1} . The situation is made worse because the current through $C_{\mbox{\scriptsize LEDO1}}$ has the effect of trying to pull the output high

(toward a CMR failure) at the same time the LED current is being reduced. For this reason, the recommended LED drive circuit (Figure 15) places the current setting resistor in series with the LED cathode. Figure 20 is the AC equivalent circuit for Figure 15 during common mode transients. In this case, the LED current is not reduced during a +dVcm/dt transient because the current flowing through the package capacitance is supplied by the power supply. During a -dVcm/dt transient, however, the LED current is reduced by the amount of current flowing through C_{LEDN}. But, better CMR performance is achieved since the current flowing in $C_{\mbox{\scriptsize LEDO1}}$ during a negative transient acts to keep the output low.

Coupling to the LED and output pins is also affected by the connection of pins 1 and 4. If CMR is limited by perturbations in the LED on current, as it is for the recommended drive circuit (Figure 15), pins 1 and 4 should be connected to the input circuit common. However, if CMR performance is limited by direct coupling to the output when the LED is off, pins 1 and 4 should be left unconnected.

CMR with the LED Off (CMR_H)

A high CMR LED drive circuit must keep the LED off $(V_F \leq V_{F(OFF)})$ during common mode transients. For example, during a +dVcm/dt transient in Figure 20, the current flowing through C_{LEDN} is supplied by the parallel combination of the LED and series resistor. As long as the voltage developed across the resistor is less than $V_{F(OFF)}$ the

LED will remain off and no common mode failure will occur. Even if the LED momentarily turns on, the 100 pF capacitor from pins 6-5 will keep the output from dipping below the threshold. The recommended LED drive circuit (Figure 15) provides about 10 V of margin between the lowest optocoupler output voltage and a 3 V IPM threshold during a $15 \text{ kV/}\mu\text{s}$ transient with V_{CM} = 1500 V. Additional margin can be obtained by adding a diode in parallel with the resistor, as shown by the dashed line connection in Figure 20, to clamp the voltage across the LED below V_{F(OFF)}.

Since the open collector drive circuit, shown in Figure 21, cannot keep the LED off during a +dVcm/dt transient, it is not desirable for applications requiring ultra high CMR_H performance. Figure 22 is the AC equivalent circuit for Figure 21 during common mode transients. Essentially all the current flowing through C_{LEDN} during a +dVcm/dt transient must be supplied by the LED. CMR_H failures can occur at dV/dt rates where the current through the LED and C_{LEDN} exceeds the input threshold. Figure 23 is an alternative drive circuit which does achieve ultra high CMR performance by shunting the LED in the off state.

IPM Dead Time and Propagation Delay Specifications

The HCPL-4506 series include a Propagation Delay Difference specification intended to help designers minimize "dead time" in their power inverter designs. Dead time is the time period during which both the high and low side power transistors (Q1 and Q2 in Figure 24) are off. Any overlap in Q1 and Q2 conduction will result in large currents flowing through the power devices between the high and low voltage motor rails.

To minimize dead time the designer must consider the propagation delay characteristics of the optocoupler as well as the characteristics of the IPM IGBT gate drive circuit. Considering only the delay characteristics of the optocoupler (the characteristics of the IPM IGBT gate drive circuit can be analyzed in the same way) it is important to know the minimum and maximum turn-on (t_{PHL}) and turn-off (t_{PLH}) propagation delay specifications, preferably over the desired operating temperature range.

The limiting case of zero dead time occurs when the input to Q1 turns off at the same time that the input to Q2 turns on. This case determines the minimum delay between LED1 turn-off and LED2 turn-on, which is related to the worst case optocoupler propagation delay waveforms, as shown in Figure 25. A minimum dead time of zero is achieved in Figure 25 when the signal to turn on

LED2 is delayed by (t_{PLH max} - t_{PHL} min) from the LED1 turn off. Note that the propagation delays used to calculate PDD are taken at equal temperatures since the optocouplers under consideration are typically mounted in close proximity to each other. (Specifically, t_{PLH max} and t_{PHL min} in the previous equation are not the same as the $t_{PLH max}$ and t_{PHL min}, over the full operating temperature range, specified in the data sheet.) This delay is the maximum value for the propagation delay difference specification which is specified at 450 ns for the HCPL-4506 series over an operating temperature range of -40°C to 100°C.

Delaying the LED signal by the maximum propagation delay difference ensures that the minimum dead time is zero, but it does not tell a designer what the maximum dead time will be. The maximum dead time occurs in the highly unlikely case where one optocoupler with the fastest t_{PLH} and another with the slowest t_{PHL} are in the same inverter leg. The maximum dead time in this case becomes the sum of the spread in the t_{PLH} and t_{PHL} propagation delays as shown in Figure 26. The maximum dead time is also equivalent to the difference between the maximum and minimum propagation delay difference specifications. The maximum dead time (due to the optocouplers) for the HCPL-4506 series is 600 ns (= 450 ns - (-150 ns)) overan operating temperature range of -40°C to 100°C.

For product information and a complete list of distributors, please go to our website: ww

www.avagotech.com

Avago, Avago Technologies, and the A logo are trademarks of Avago Technologies Limited in the United States and other countries. Data subject to change. Copyright © 2006 Avago Technologies Limited. All rights reserved. Obsoletes 5989-2113EN AV01-0551EN October 11, 2006

